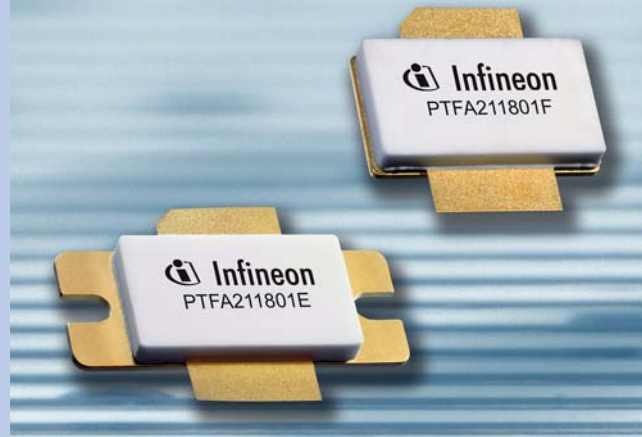


# PTFA211801E PTFA211801F

WCDMA RF Power FET



The PTFA211801E and PTFA211801F Two devices from our next generation of GOLDMOS devices, these high-gain devices bring rugged quality to your amplifier designs. Specifically optimized for WCDMA applications, the PTFA211801E and PTFA211801F deliver up to 180 W under CW conditions. These internally matched GOLDMOS<sup>®</sup> FETs are single-ended and laterally diffused, and operate with 15.5 dB linear gain. Full gold metallization and integrated ESD protection ensure excellent device lifetime and reliability.

### Features

- Optimized for 2110 MHz to 2170 MHz
- Thermally Enhanced Packaging
- Proven ruggedness
- Broadband internal matching
- Full gold metallization
- Integrated ESD protection: Human Body Model, Class 1 (minimum)
- Excellent thermal stability
- Low HCl drift
- Capable of handling 10:1 VSWR @ 30V, 180 W (CW) output power
- Qualified for operation up to 32 V

### Performance

- Typical two-carrier 3GPP WCDMA performance
  - Average output power = 45 W
  - Gain = 15.5 dB
  - Efficiency = 28%
  - IM3 = -37 dBc
  - ACPR < -42 dBc
  - 10 MHz carrier spacing
  - Channel BW = 3.84 MHz
- Thermal Resistance = 0.22 °C/W

### Type List

| Type        | Output Power | Linear Gain | Supply Voltage | Package Type                | Package |
|-------------|--------------|-------------|----------------|-----------------------------|---------|
| PTFA211801E | 180 W        | 15.5 dB     | 28 - 32 V      | Thermally enhanced          | 30260   |
| PTFA211801F | 180 W        | 15.5 dB     | 28 - 32 V      | Thermally enhanced, earless | 31260   |

[www.infineon.com/rfpower](http://www.infineon.com/rfpower)

Wireless Communication



Never stop thinking.

How to reach us:  
<http://www.infineon.com/rfpower>

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**Information**

For further information on technology, delivery terms and conditions and prices please contact your nearest Infineon Technologies Office.

**Warnings**

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